# NSN 5961-00-938-3499

Transistor - Page 1 of 2



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Inclosure Material:

Metal

**Overall Length:** 

1.140 inches

# **Overall Diameter:**

1.280 inches

# Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

## Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 1.00 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

Transfer Ratio:

500.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

#### Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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- Demilitarization:

Yes - demil/mli

# **NSN 5961-00-938-3499** Transistor - Page 2 of 2

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